Unit: mm

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type ($L^2 - \pi - MOS V$)

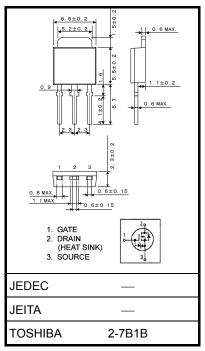
2SK4018

Chopper Regulator, DC/DC Converter and Motor Drive Applications

- 4 V gate drive
- Low drain-source ON-resistance : $R_{DS (ON)} = 0.28 \Omega$ (typ.)
- High forward transfer admittance : |Y_{fs}| = 3.5 S (typ.)
- Low leakage current $: I_{DSS} = 100 \ \mu A \ (max) \ (V_{DS} = 100 \ V)$
- Enhancement mode : V_{th} = 0.8~2.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Character	istic	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	100	V
Drain-gate voltage (R _{GS} = 20 kΩ)		V _{DGR}	100	V
Gate-source voltage		V _{GSS}	±20	V
Drain current	DC (Note 1)	ID	3	А
	Pulse (Note 1)	I _{DP}	12	А
Drain power dissipatio	n (Tc = 25°C)	PD	20	W
Single-pulse avalanche energy (Note 2)		E _{AS}	140	mJ
Avalanche current		I _{AR}	3	А
Repetitive avalanche energy (Note 3)		E _{AR}	2	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55~150	°C



Weight: 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

Characteristic	Symbol	Мах	Unit
Thermal resistance, channel to case	R _{th (ch−c)}	6.25	°C / W
Thermal resistance, channel to ambient	R _{th (ch−a)}	125	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 50 V, T_{ch} = 25°C (initial), L = 25 mH, R_G = 25 Ω , I_{AR} = 3 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

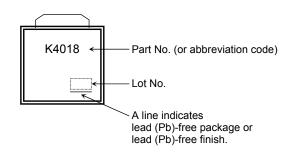
Electrical Characteristics (Ta = 25°C)

Chara	cteristic	Symbol	Test Condition	Min	Тур.	Мах	Unit
Gate leakage cu	ırrent	I _{GSS}	V_{GS} = ±16 V, V_{DS} = 0 V	_	_	±10	μA
Drain cutoff curr	ent	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V	_	_	100	μA
Drain−source br voltage	eakdown	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	100	_	_	V
Gate threshold	voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	0.8	_	2.0	V
Drain-source ON-resistance		R _{DS (ON)}	V _{GS} = 4 V, I _D = 2 A	_	0.36	0.45	Ω
			V _{GS} = 10 V, I _D = 2 A	_	0.28	0.35	
Forward transfe	r admittance	Y _{fs}	V _{DS} = 10 V, I _D = 2 A	1.5	3.5	_	S
Input capacitant	ce	C _{iss}		_	280	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	50	_	pF
Output capacitance		C _{oss}		_	105	_	
Switching time	Rise time	tr	$v_{GS} \stackrel{10V}{_{0V}} \prod_{I_D = 2A \\ V \cup I_T \\ C \cup I_T$	_	20	_	
	Turn-on time	t _{on}		_	50	_	ns
	Fall time	t _f		_	40	_	115
	Turn-off time	t _{off}	Duty $\leq 1\%$, t _w =10 μ s	_	170	_	
Total gate charge (gate-source plus gate-drain)		Qg			13.5	_	
Gate-source charge		Q _{gs}	V _{DD} ≈ 80 V, V _{GS} = 10 V, I _D = 3 A		8.5	_	nC
Gate-drain ("Miller") charge		Q _{gd}]		5	_	

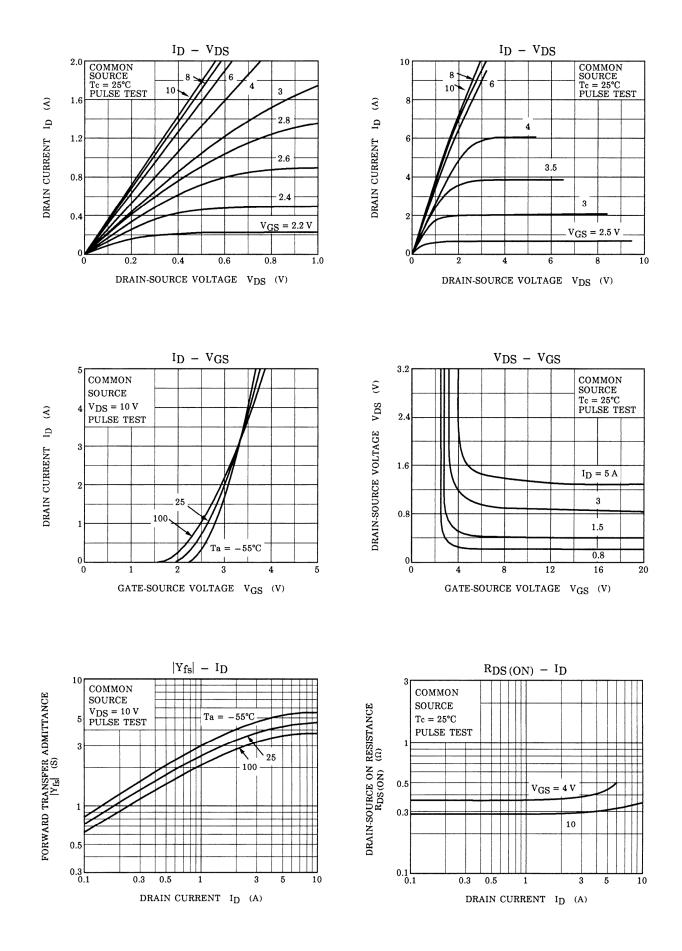
Source–Drain Ratings and Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	3	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_		12	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 3 A, V _{GS} = 0 V	_	-	-1.5	V
Reverse recovery time	t _{rr}	I_{DR} = 3 A, V_{GS} = 0 V, dI_{DR} / dt = 50 A / μ s	_	100	_	ns
Reverse recovery charge	Q _{rr}		_	0.2	_	μC

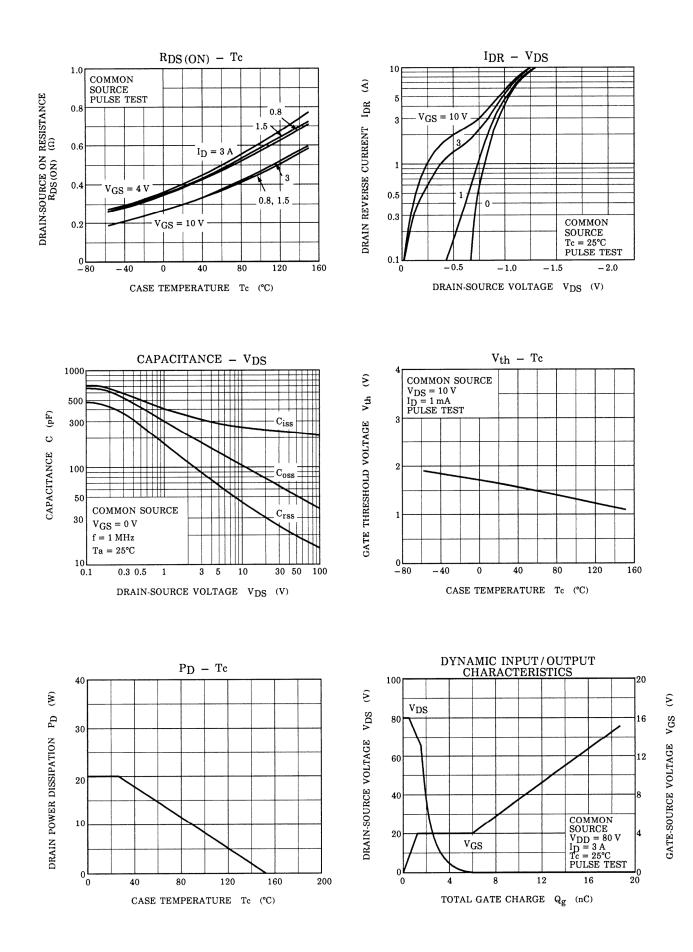
Marking

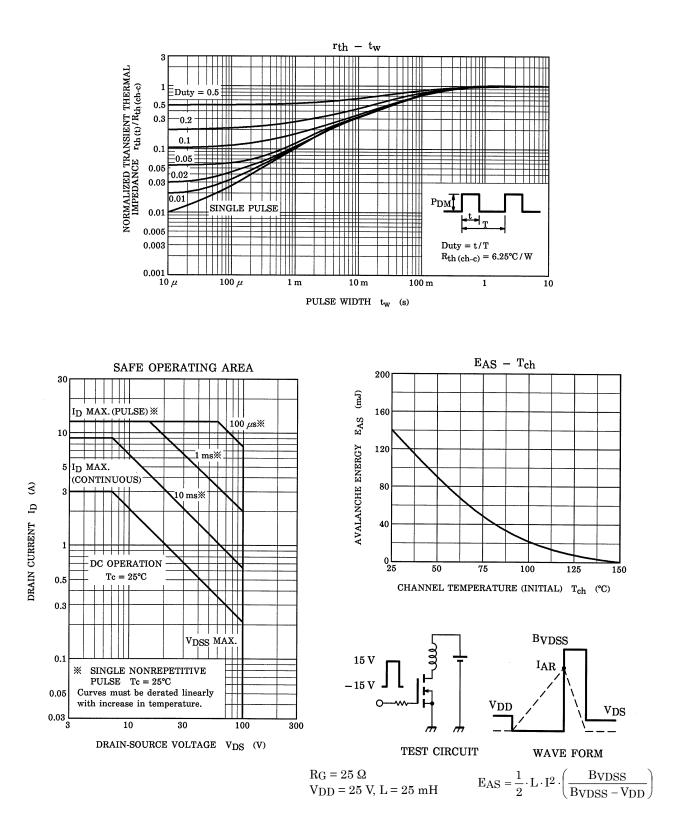


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